

AN48840B

Low current consumption, high sensitivity CMOS Hall IC
 Alternating magnetic field operation
 (For low-speed rotation detection)

Overview

The AN48840B is a Hall ICs (a magnetic sensor) which has 2 times or more sensitivity and a low current consumption of about one fiftieth compared with our conventional one.

In this Hall IC, a Hall element, a offset cancel circuit, an amplifier circuit, a sample and hold circuit, a Schmidt circuit, and output stage FET are integrated on a single chip housed in a small package by IC technique.

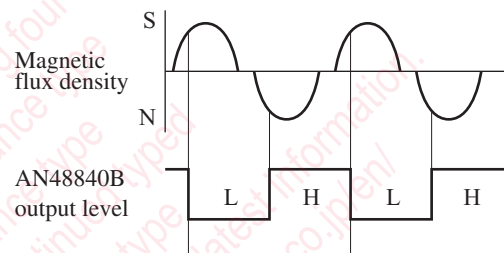
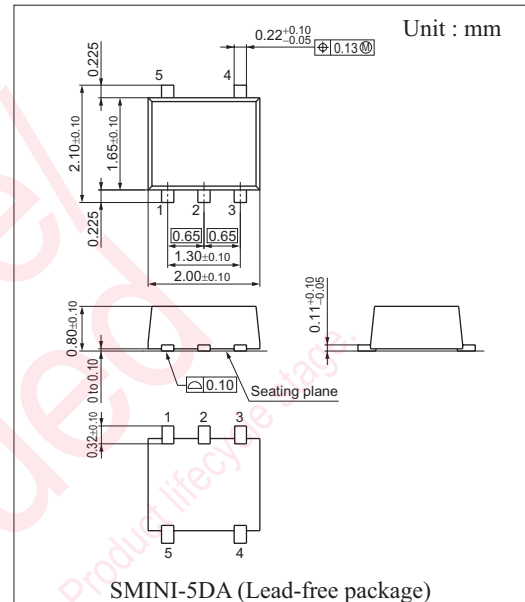
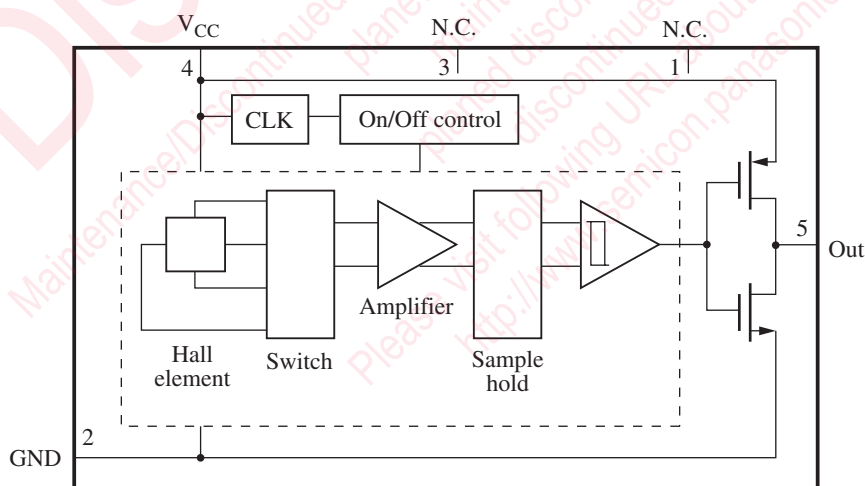
Features

- High sensitivity due to offset cancel circuit and a new sample and hold circuit
- Small current by using intermittent action
 (Average supply current: 56 μ A typ., Sampling period: 670 μ s typ.)
- Small package (SMD)
- CMOS inverter output (logic output form)

Applications

- Functional operation key, Mouse,
 Appliances for low-speed rotation detection

Block Diagram



Pin Descriptions

Pin No.	Symbol	Description	Pin No.	Symbol	Description
1	N.C.	—	4	V _{CC}	Power supply
2	GND	Ground	5	Out	Output
3	N.C.	—			

■ Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Supply voltage	V _{CC}	5	V
Output voltage	V _{OUT}	5	V
Supply current	I _{CC}	5	mA
Output current	I _{OUT}	15	mA
Power dissipation *1, *2	P _D	60	mW
Operating ambient temperature *1	T _{opr}	-25 to +75	°C
Storage temperature *1	T _{stg}	-55 to +125	°C

Note) *1: Except for the power dissipation, operating ambient temperature and storage temperature, all ratings are for T_a = 25°C.

*2: T_a = 75°C. For the independent IC without a heat sink. Please use within the range of power dissipation, referring to P_D — T_a curve.

■ Recommended Operating Range

Parameter	Symbol	Range	Unit
Supply voltage	V _{CC}	2.5 to 3.5	V

■ Electrical Characteristics T_a = 25°C ± 2°C

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Operating magnetic flux density 1 *1	B _{H-L}	V _{CC} = 3 V, V _{CC} = 2.5 V	0.5	—	6	mT
Operating magnetic flux density 2 *2	B _{L-H}	V _{CC} = 3 V, V _{CC} = 2.5 V	-6	—	-0.5	mT
Output voltage 1	V _{OL1}	V _{CC} = 3 V, I _O = 2 mA, B = 6.0 mT	—	0.1	0.3	V
Output voltage 1	V _{OL2}	V _{CC} = 2.5 V, I _O = 2 mA, B = 6.0 mT	—	0.1	0.3	V
Output voltage 2	V _{OH1}	V _{CC} = 3 V, I _O = -2 mA, B = -6.0 mT	2.7	2.9	—	V
Output voltage 2	V _{OH2}	V _{CC} = 2.5 V, I _O = -2 mA, B = -6.0 mT	2.7	2.9	—	V
Supply current 1 *3	I _{CCAVE}	V _{CC} = 3 V	—	56.0	85.0	μA
Supply current 2 *3	I _{CC2AVE}	V _{CC} = 2.5 V	—	48.0	72.0	μA
Intermittent action time	T _{sam}	V _{CC} = 3 V	490	670	850	μS
Intermittent action time 2	T _{sam2}	V _{CC} = 2.5 V	513	710	890	μS

Note) *1: Symbol B_{H-LS}, B_{H-LN} stands for the operating magnetic flux density where its output level varies from high to low.

*2: Symbol B_{L-HS}, B_{L-HN} stands for the operating magnetic flux density where its output level varies from low to high.

*3: $I_{CCAVE} = \{I_{CCON} \times t_{ON} + I_{CCOFF} \times t_{OFF}\} / \{t_{ON} + t_{OFF}\}$

• Design reference data

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Hysteresis width	BW	V _{CC} = 3 V	—	7	—	mT
Supply current 3	I _{CCON}	V _{CC} = 3 V	—	1.4	2.1	mA
Supply current 4	I _{CCOFF}	V _{CC} = 3 V	—	2.5	—	μA
Supply current 5	I _{CC2ON}	V _{CC} = 2.5 V	—	1.12	1.68	mA
Supply current 6	I _{CC2OFF}	V _{CC} = 2.5 V	—	2.2	—	μA
Operating time	t _{ON}	T _a = -25°C to 75°C, V _{CC} = 3 V	10	26	42	μS
Stop time	t _{OFF}	T _a = -25°C to 75°C, V _{CC} = 3 V	258	644	1 030	μS
Operating time 2	t _{2ON}	T _a = -25°C to 75°C, V _{CC} = 2.5 V	11	27	43	μS
Stop time 2	t _{2OFF}	T _a = -25°C to 75°C, V _{CC} = 2.5 V	270	674	1 078	μS

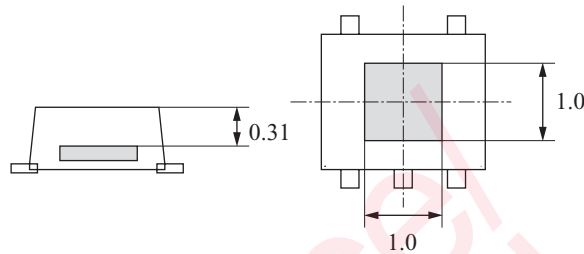
Note) It will operate normally in approximately 0.67 ms after power on.

■ Technical Data

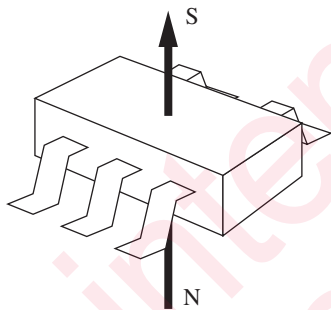
- Position of a Hall element (unit in mm)

Distance from a package surface to sensor part: 0.31 mm (reference value)

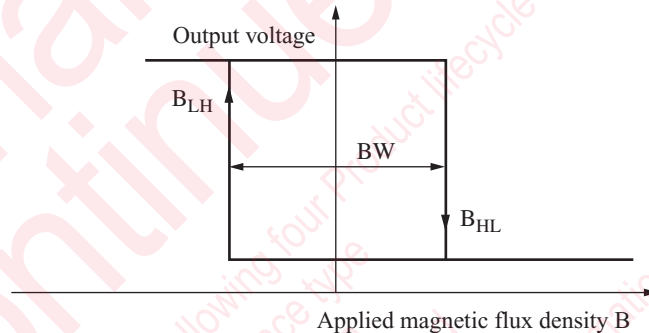
A Hall element is placed on the shaded part in the figure.



- Magneto-electro conversion characteristics



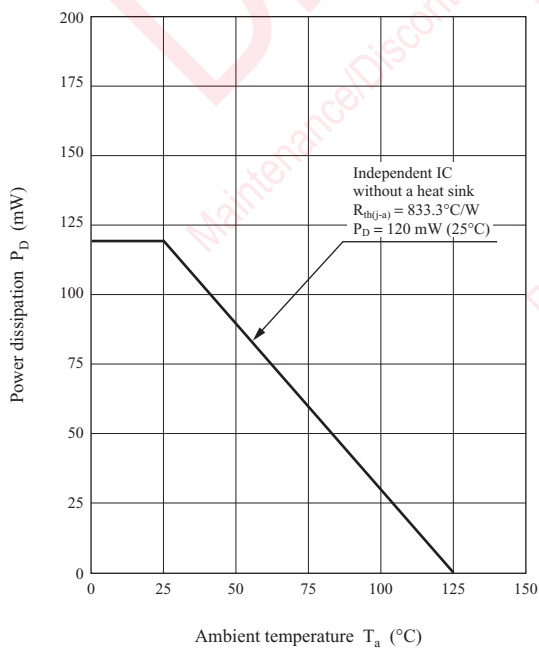
Direction of applied magnetic field



Operating magnetic flux density

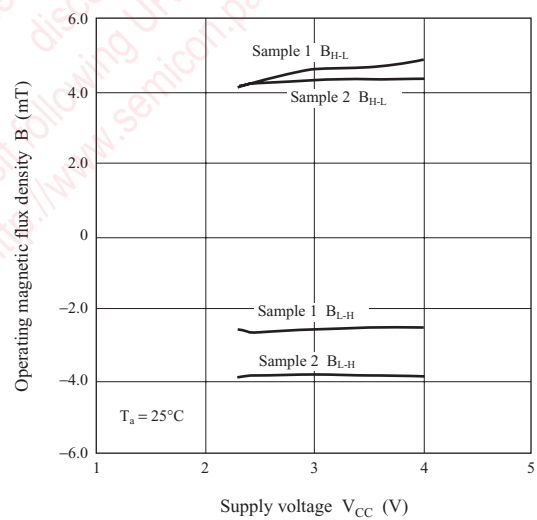
- Power dissipation of package SMINI-5DA

$P_D - T_a$



- AN48840B Main characteristics

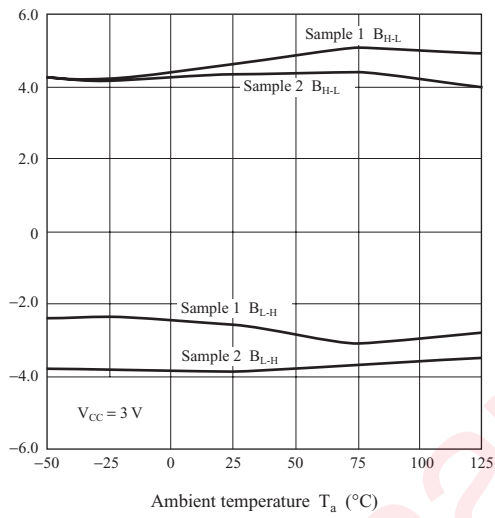
Operating magnetic flux density — Supply voltage



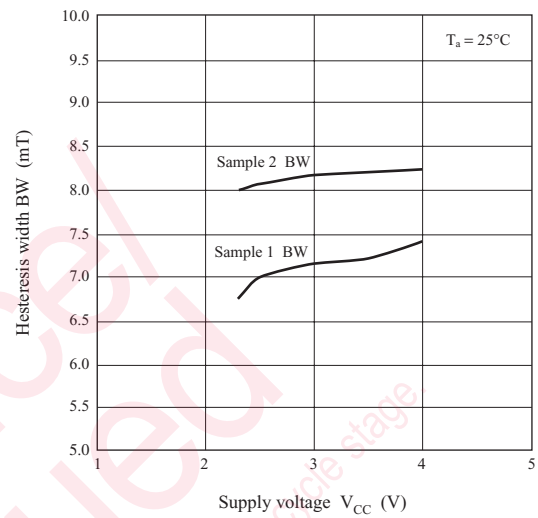
■ Technical Data (continued)

- AN48840B Main characteristics (continued)

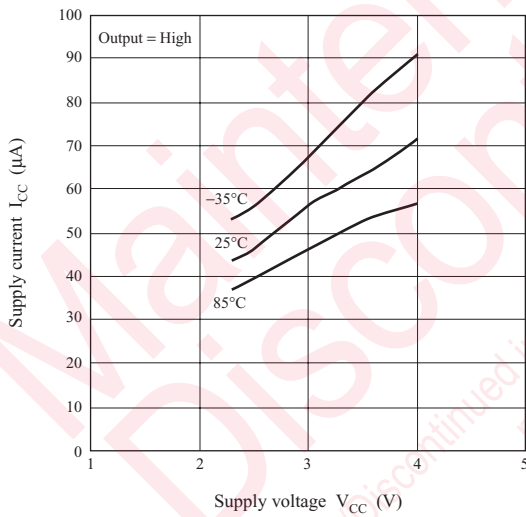
Operating magnetic flux density — Ambient temperature



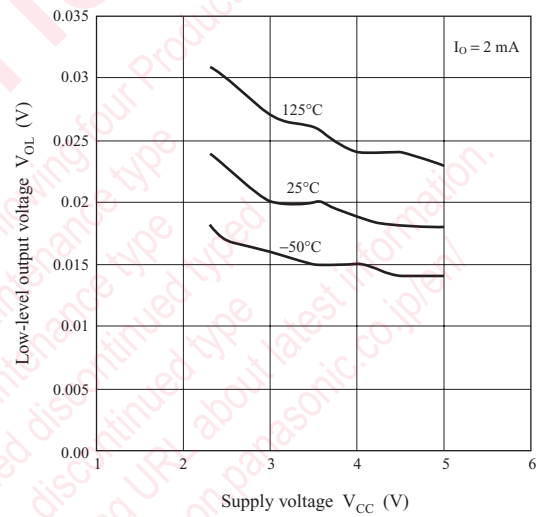
Hysteresis width — Supply voltage



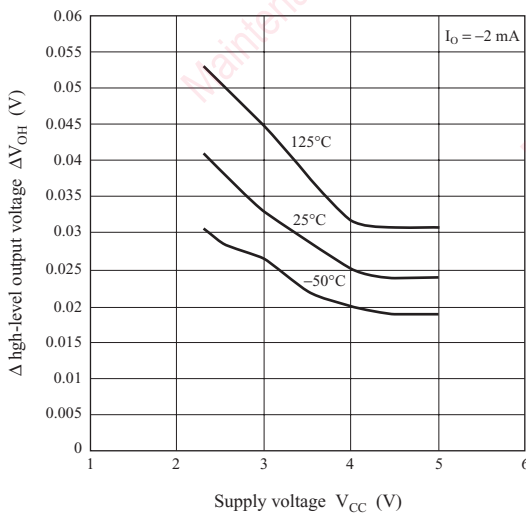
Supply current — Supply voltage



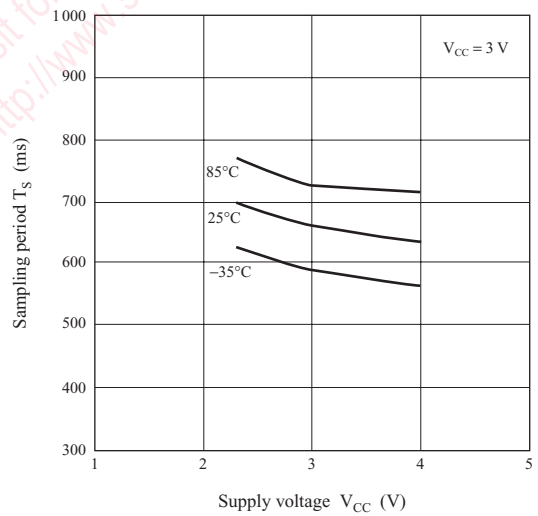
Low-level output voltage — Supply voltage



Δ high-level output voltage — Supply voltage



Sampling period — Supply voltage



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